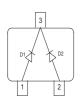


Silicon Variable Capacitance Diodes

- For FM radio tuners with extended frequency band
- High tuning ratio at low supply voltage (car radio)
- Monolithic chip (common cathode) for perfect dual diode tracking
- Coded capacitance groups and group matching available
- Pb-free (RoHS compliant) package



BB814

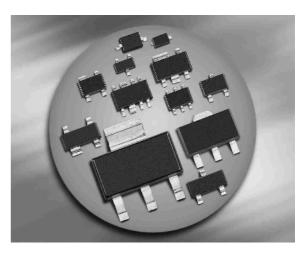


Туре	Package	Configuration	L _S (nH)	Marking
BB814	SOT23	common cathode	1.8	SH1/2*

*For differences see next page Capacitance groups

Maximum Ratings at $T_A = 25^{\circ}$ C, unless otherwise specified

Parameter	Symbol	Value	Unit
Diode reverse voltage	V _R	18	V
Peak reverse voltage-	V _{RM}	20	
Forward current	I _F	50	mA
Operating temperature range	T _{op}	-55 125	°C
Storage temperature	T _{sta}	-55 150	





Symbol		Values		
	min.	typ.	max.	1
·				
I _R				nA
	-	-	20	
	-	-	200	
CT				pF
	43	44.75	46.5	
	19.1	20.8	22.7	
C _{T2} /C _{T8}	2.05	2.15	2.25	
$\Delta C_{T}/C_{T}$	-	-	3	%
r _S	-	0.18	-	Ω
Q	-	200	-	
	$ \begin{array}{c} I_{R} \\ \hline \\ \\ \\ \\ \\ \\ \\ \\ \\ \\ \\ \\ \\ $	$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	$\begin{array}{c c c c c c c }\hline & & & & & & & & & & & & & & & & & & &$	$\begin{array}{c c c c c c c c c c c c c c c c c c c $

Electrical Characteristics at $T_A = 25^{\circ}$ C, unless otherwise specified

 1 Capacitance groups at 2V and 8V, coded 1; 2 $C_{T}/groups$ 1 2

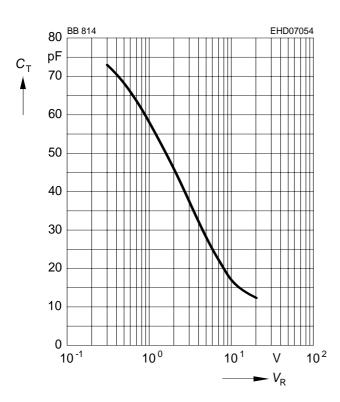
C _{2V}	min	43pF	44.5pF
C _{2V}	max	45pF	46.5pF
C_{8V}	min	19.1pF	19.75pF
C _{8V}	max	21.95pF	22.7pF

²For details please refer to Application Note 047.



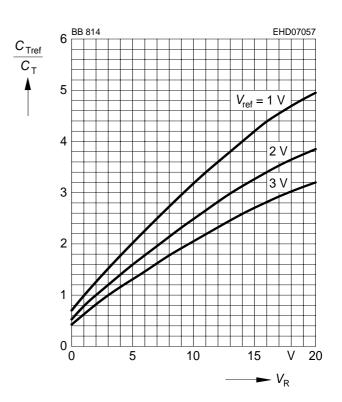
Diode capacitance $C_{T} = f(V_{R})$

f = 1 MHz

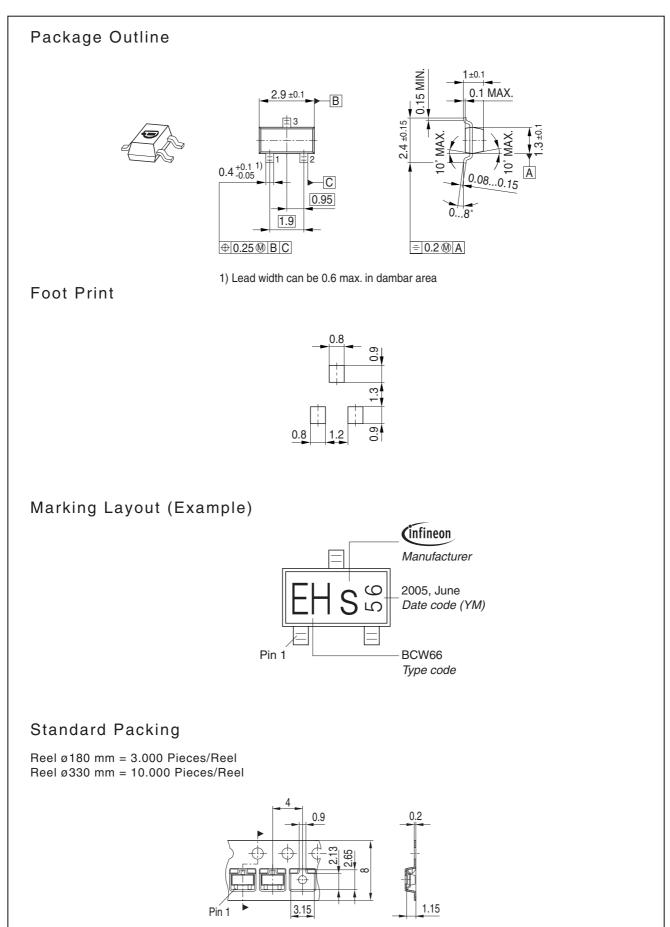


Capacitance ratio $C_{\text{Tref}}/C_{\text{T}} = f(V_{\text{R}})$

f = 1 MHz









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